勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-54151736 胜特力电子(深圳) 86-755-83298787

Http://www.100y.com.tw

**Preferred Device** 

# PNP Silicon Epitaxial Transistor

This PNP Silicon Epitaxial Transistor is designed for use in low voltage, high current applications. The device is housed in the SOT-223-4 package, which is designed for medium power surface mount applications.

- High Current:  $I_C = -1.0 \text{ A}$
- The SOT-223-4 Package can be soldered using wave or reflow.
- SOT-223-4 package ensures level mounting, resulting in improved thermal conduction, and allows visual inspection of soldered joints.
   The formed leads absorb thermal stress during soldering, eliminating the possibility of damage to the die.
- Available in 12 mm Tape and Reel
   Use BCP69T1 to order the 7 inch/1000 unit reel.
   Use BCP69T3 to order the 13 inch/4000 unit reel.
- NPN Complement is BCP68
- Pb–Free Package May be Available. The G–Suffix Denotes a Pb–Free Lead Finish

### **MAXIMUM RATINGS** (T<sub>C</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	$V_{CEO}$	-20	Vdc
Collector-Base Voltage	$V_{CBO}$	-25	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	-5.0	Vdc
Collector Current	Ic	-1.0	Adc
Total Power Dissipation @ T <sub>A</sub> = 25°C (Note 1) Derate above 25°C	P <sub>D</sub>	1.5 12	W mW/°C
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to 150	°C

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance – Junction–to–Ambient (Surface Mounted)	$R_{\theta JA}$	83.3	°C/W
Lead Temperature for Soldering, 0.0625 in from case	TL	260	°C
Time in Solder Bath	001.C	10	Sec

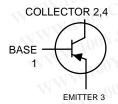
1. Device mounted on a glass epoxy printed circuit board 1.575 in. x 1.575 in. x 0.059 in.; mounting pad for the collector lead min. 0.93 sq. in.

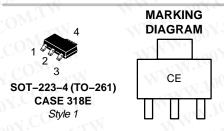


### ON Semiconductor®

http://onsemi.com

MEDIUM POWER
PNP SILICON
HIGH CURRENT
TRANSISTOR
SURFACE MOUNT





CE = Specific Device Code

### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
BCP69T1	SOT-223-4	1000 / Tape & Reel
BCP69T1G	SOT-223-4	1000 / Tape & Reel
ВСР69Т3	SOT-223-4	4000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

**Preferred** devices are recommended choices for future use and best overall value.

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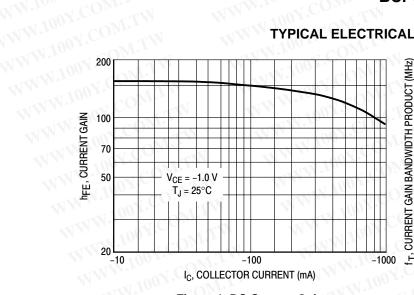
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Characteristics	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	MM	100Y	Live	V	
Collector–Emitter Breakdown Voltage ( $I_C = -100 \mu Adc$ , $I_E = 0$ )	V <sub>(BR)CES</sub>	-25	COM	- W	Vdc
Collector–Emitter Breakdown Voltage ( $I_C = -1.0 \text{ mAdc}$ , $I_B = 0$ )	V <sub>(BR)CEO</sub>	-20	A.COM	TVT	Vdc
Emitter–Base Breakdown Voltage ( $I_E = -10 \mu Adc$ , $I_C = 0$ )	V <sub>(BR)EBO</sub>	-5.0	CON	- TV	Vdc
Collector–Base Cutoff Current (V <sub>CB</sub> = -25 Vdc, I <sub>E</sub> = 0)	I <sub>CBO</sub>	- VI-VI-VI		-10	μAdo
Emitter–Base Cutoff Current (V <sub>EB</sub> = -5.0 Vdc, I <sub>C</sub> = 0)	I <sub>EBO</sub>	- TON 1	007	-10	μAdo
ON CHARACTERISTICS	TW	MM	100 Y.C.	WT.Wo	
DC Current Gain $(I_C = -5.0 \text{ mAdc}, V_{CE} = -10 \text{ Vdc})$ $(I_C = -500 \text{ mAdc}, V_{CE} = -1.0 \text{ Vdc})$ $(I_C = -1.0 \text{ Adc}, V_{CE} = -1.0 \text{ Vdc})$	TWhFE	50 85 60	M:100X	- 375 -	
Collector–Emitter Saturation Voltage (I <sub>C</sub> = -1.0 Adc, I <sub>B</sub> = -100 mAdc)	V <sub>CE(sat)</sub>		1W-100	-0.5	Vdc
Base–Emitter On Voltage ( $I_C = -1.0 \text{ Adc}$ , $V_{CE} = -1.0 \text{ Vdc}$ )	V <sub>BE(on)</sub>	- 111	T 100	-1.0	Vdc
DYNAMIC CHARACTERISTICS	WILL	V	11	00Y.C	M.T
Current–Gain – Bandwidth Product ( $I_C = -10 \text{ mAdc}$ , $V_{CE} = -5.0 \text{ Vdc}$ )	f <sub>T</sub> TW	- 1	60	1007-CE	MHz

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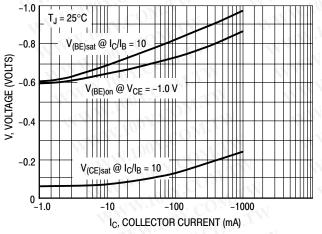


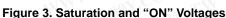


(MHz) **CURRENT GAIN BANDWIDTH PRODUCT** 200 100  $V_{CE} = -10 \text{ V}$  $T_J = 25^{\circ}C$ 70 f = 30 MHz 50 30 <u>L</u> -100 -1000 IC, COLLECTOR CURRENT (mA)

Figure 1. DC Current Gain

Figure 2. Current Gain Bandwidth Product





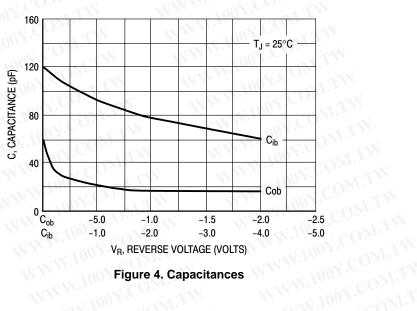


Figure 4. Capacitances

### PACKAGE DIMENSIONS

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NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M. 1982.
- 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.249	0.263	6.30	6.70	
В	0.130	0.145	3.30	3.70	
С	0.060	0.068	1.50	1.75	
D	0.024	0.035	0.60	0.89	
F	0.115	0.126	2.90	3.20	
G	0.087	0.094	2.20	2.40	
Н	0.0008	0.0040	0.020	0.100	
J	0.009	0.014	0.24	0.35	
K	0.060	0.078	1.50	2.00	
L	0.033	0.041	0.85	1.05	
M	0°	10 °	0 °	10 °	
S	0.264	0.287	6.70	7.30	

STYLE 1: PIN 1 BAS

- PIN 1. BASE 2. COLLECTOR
  - 3. EMITTER 4. COLLECTOR
- **SOLDERING FOOTPRINT\***

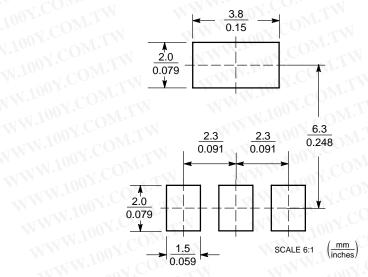


Figure 5. SOT-223

\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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